#### Tuan V Vu

# List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

180
papers

2,934
citations

31
h-index
g-index

189
ext. papers

3,966
ext. citations

3.2
avg, IF

L-index

#	Paper	IF	Citations
180	Tunable type-II band alignment and electronic structure of C3N4/MoSi2N4 heterostructure: Interlayer coupling and electric field. <i>Physical Review B</i> , <b>2022</b> , 105,	3.3	9
179	Janus monolayer HfSO with improved optical properties as a novel material for photovoltaic and photocatalyst applications. <i>New Journal of Chemistry</i> , <b>2022</b> , 46, 1557-1568	3.6	1
178	Growth of a novel K0.4Rb0.6Pb2Cl5 crystal and theoretical and experimental studies of its electronic and optical properties. <i>Optical Materials</i> , <b>2022</b> , 124, 112050	3.3	O
177	Structural, electronic, and transport properties of quintuple atomic Janus monolayers Ga2SX2 (X= O, S, Se, Te): First-principles predictions. <i>Physical Review B</i> , <b>2022</b> , 105,	3.3	6
176	Highly anisotropic layered crystal AgBiP2Se6: Growth, electronic band-structure and optical properties. <i>Materials Chemistry and Physics</i> , <b>2022</b> , 277, 125556	4.4	О
175	First-principles investigations of Ba2NaIO6 double Perovskite semiconductor: Material for low-cost energy technologies. <i>Materials Chemistry and Physics</i> , <b>2022</b> , 275, 125237	4.4	2
174	Novel Janus GaInX (X = S, Se, Te) single-layers: first-principles prediction on structural, electronic, and transport properties <i>RSC Advances</i> , <b>2022</b> , 12, 7973-7979	3.7	О
173	Layered post-transition-metal dichalcogenide SnGeN as a promising photoelectric material: a DFT study <i>RSC Advances</i> , <b>2022</b> , 12, 10249-10257	3.7	1
172	Monoelemental two-dimensional iodinene nanosheets: a first-principles study of the electronic and optical properties. <i>Journal Physics D: Applied Physics</i> , <b>2022</b> , 55, 135104	3	
171	Intriguing interfacial characteristics of the CS contact with MX (M = Mo, W; X = S, Se, Te) and MXY $((X \square Y) = S, Se, Te)$ monolayers <i>RSC Advances</i> , <b>2022</b> , 12, 12292-12302	3.7	0
170	Theoretical prediction of Janus PdXO (X = S, Se, Te) monolayers: structural, electronic, and transport properties <i>RSC Advances</i> , <b>2022</b> , 12, 12971-12977	3.7	О
169	Electronic and optical properties of bulk and surface of CsPbBr inorganic halide perovskite a first principles DFT 1/2 approach. <i>Scientific Reports</i> , <b>2021</b> , 11, 20622	4.9	9
168	Electric gating and interlayer coupling controllable electronic structure and Schottky contact of graphene/Bil3 van der Waals heterostructure. <i>Physical Review B</i> , <b>2021</b> , 103,	3.3	13
167	Electronic structure and optical constants of CsPbCl3: The effect of approaches within ab initio calculations in relation to X-ray spectroscopy experiments. <i>Materials Chemistry and Physics</i> , <b>2021</b> , 261, 124216	4.4	4
166	DFT calculations and experimental studies of the electronic structure and optical properties of Tl4PbI6. <i>Optical Materials</i> , <b>2021</b> , 114, 110982	3.3	4
165	Interfacial Electronic Properties and Tunable Contact Types in Graphene/Janus MoGeSiN Heterostructures. <i>Journal of Physical Chemistry Letters</i> , <b>2021</b> , 12, 3934-3940	6.4	17
164	Electronic, optical, and thermoelectric properties of Janus In-based monochalcogenides. <i>Journal of Physics Condensed Matter</i> , <b>2021</b> , 33,	1.8	9

## (2021-2021)

163	Two-Dimensional Boron Phosphide/MoGeN van der Waals Heterostructure: A Promising Tunable Optoelectronic Material. <i>Journal of Physical Chemistry Letters</i> , <b>2021</b> , 12, 5076-5084	6.4	21	
162	A DFT Study of Structural, Elastic, Thermodynamic, Magneto-optical, and Electrical Properties of Double-Perovskite Bi2CrMO6 (M = Zn, Ni) Using GGA and TB-mBj Functionals. <i>Journal of Superconductivity and Novel Magnetism</i> , <b>2021</b> , 34, 2105-2119	1.5	2	
161	Theoretical analysis of the HfS2 monolayer electronic structure and optical properties under vertical strain effects. <i>Optik</i> , <b>2021</b> , 225, 165718	2.5	6	
160	Ab initio study of the structural, electronic, optical and elastic properties of promising optoelectronic and thermoelectric compounds MgSc2X4 (X = S; Se). <i>Journal of Solid State Chemistry</i> , <b>2021</b> , 293, 121763	3.3	2	
159	Crystal growth, electronic and optical properties of Tl2CdSnSe4, a recently discovered prospective semiconductor for application in thin film solar cells and optoelectronics. <i>Optical Materials</i> , <b>2021</b> , 111, 110656	3.3	8	
158	Induced ferromagnetism in bilayer hexagonal Boron Nitride (h-BN) on vacancy defects at B and N sites. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2021</b> , 126, 114436	3	9	
157	Strain-tunable electronic, optical and thermoelectric properties of BP monolayer investigated by FP-LAPW calculations. <i>Physica B: Condensed Matter</i> , <b>2021</b> , 603, 412757	2.8	3	
156	First-principles investigation of structural, elastic, thermodynamic, electronic and optical properties of lead-free double perovskites halides: Cs2LiYX6 (X = Br, I). <i>Materials Chemistry and Physics</i> , <b>2021</b> , 258, 123945	4.4	11	
155	Electronic and optical properties of gyrotropic Hg3S2Cl2: insights from an ab initio study. <i>Indian Journal of Physics</i> , <b>2021</b> , 95, 73-82	1.4	0	
154	Structural, elastic, and electronic properties of chemically functionalized boron phosphide monolayer <i>RSC Advances</i> , <b>2021</b> , 11, 8552-8558	3.7	3	
153	Stacking effects in van der Waals heterostructures of blueP and Janus XYO (X = Ti, Zr, Hf: Y = S, Se) monolayers <i>RSC Advances</i> , <b>2021</b> , 11, 12189-12199	3.7	4	
152	Outstanding elastic, electronic, transport and optical properties of a novel layered material CF: first-principles study <i>RSC Advances</i> , <b>2021</b> , 11, 23280-23287	3.7	3	
151	A van der Waals heterostructure of MoS2/MoSi2N4: a first-principles study. <i>New Journal of Chemistry</i> , <b>2021</b> , 45, 8291-8296	3.6	20	
150	Theoretical prediction of electronic, transport, optical, and thermoelectric properties of Janus monolayers In2XO (X=S,Se,Te). <i>Physical Review B</i> , <b>2021</b> , 103,	3.3	39	
149	Theoretical insights into tunable electronic and optical properties of Janus Al2SSe monolayer through strain and electric field. <i>Optik</i> , <b>2021</b> , 238, 166761	2.5	2	
148	Quantum magnetotransport properties of silicene: Influence of the acoustic phonon correction. <i>Physical Review B</i> , <b>2021</b> , 104,	3.3	1	
147	Oxygenation of Janus group III monochalcogenides: First-principles insights into GaInXO (X=S, Se, Te) monolayers. <i>Physical Review B</i> , <b>2021</b> , 104,	3.3	12	
146	A theoretical study on elastic, electronic, transport, optical and thermoelectric properties of Janus SnSO monolayer. <i>Journal Physics D: Applied Physics</i> , <b>2021</b> , 54, 475306	3	3	

145	Quaternary Tl2CdGeSe4 selenide: Electronic structure and optical properties of a novel semiconductor for potential application in optoelectronics. <i>Journal of Solid State Chemistry</i> , <b>2021</b> , 302, 122453	3.3	1
144	First-principles calculations to investigate electronic properties of ZnO/PtSSe van der Waals heterostructure: Effects of vertical strain and electric field. <i>Chemical Physics</i> , <b>2021</b> , 551, 111333	2.3	1
143	Effects of electric field and biaxial strain on the (NO2, NO, O2, and SO2) gas adsorption properties of Sc2CO2 monolayer. <i>Superlattices and Microstructures</i> , <b>2021</b> , 107135	2.8	1
142	Quaternary Cu2HgGeSe4 selenide: Its electronic and optical properties as elucidated from TB-mBJ band-structure calculations and XPS and XES measurements. <i>Chemical Physics</i> , <b>2020</b> , 536, 110821	2.3	5
141	Electronic and optical properties of a Janus SnSSe monolayer: effects of strain and electric field. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 11637-11643	3.6	33
140	Magneto-optical absorption in silicene and germanene induced by electric and Zeeman fields. <i>Physical Review B</i> , <b>2020</b> , 101,	3.3	17
139	Graphene hetero-multilayer on layered platinum mineral jacutingaite (Pt2HgSe3): van der Waals heterostructures with novel optoelectronic and thermoelectric performances. <i>Journal of Materials Chemistry A</i> , <b>2020</b> , 8, 13248-13260	13	44
138	LiCl monolayer for UV detection: First principles prediction. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 123, 114168	3	3
137	First-principles investigation of nonmetal doped single-layer BiOBr as a potential photocatalyst with a low recombination rate. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 15354-15364	3.6	45
136	Interlayer coupling and electric field controllable Schottky barriers and contact types in graphene/PbI2 heterostructures. <i>Physical Review B</i> , <b>2020</b> , 101,	3.3	45
135	Theoretical and experimental study on the electronic and optical properties of KRbPbBr: a promising laser host material <i>RSC Advances</i> , <b>2020</b> , 10, 11156-11164	3.7	4
134	First-principles prediction of chemically functionalized InN monolayers: electronic and optical properties <i>RSC Advances</i> , <b>2020</b> , 10, 10731-10739	3.7	10
133	Effects of electric field and strain engineering on the electronic properties, band alignment and enhanced optical properties of ZnO/Janus ZrSSe heterostructures <i>RSC Advances</i> , <b>2020</b> , 10, 9824-9832	3.7	9
132	Effects of different surface functionalization on the electronic properties and contact types of graphene/functionalized-GeC van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 7952-7961	3.6	15
131	DFT study and XPS measurements elucidating the electronic and optical properties of KPb2Cl5. <i>Optical Materials</i> , <b>2020</b> , 102, 109793	3.3	7
130	Structural, electronic and optical properties of CdO monolayer and bilayers: Stacking effect investigations. <i>Superlattices and Microstructures</i> , <b>2020</b> , 145, 106644	2.8	8
129	Ni-doped WO3 flakes-based sensor for fast and selective detection of H2S. <i>Journal of Materials Science: Materials in Electronics</i> , <b>2020</b> , 31, 12783-12795	2.1	3
128	Electronic and optoelectronic properties of van der Waals heterostructure based on graphene-like GaN, blue phosphorene, SiC, and ZnO: A first principles study. <i>Journal of Applied Physics</i> , <b>2020</b> , 127, 245	3 <del>0</del> 2	7

## (2020-2020)

127	Computational prediction of electronic and optical properties of Janus Ga2SeTe monolayer. Journal Physics D: Applied Physics, <b>2020</b> , 53, 455302	3	13	
126	Stacking and electric field effects on the band alignment and electronic properties of the GeC/GaSe heterostructure. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 120, 114050	3	7	
125	The characteristics of defective ZrS2 monolayers adsorbed various gases on S-vacancies: A first-principles study. <i>Superlattices and Microstructures</i> , <b>2020</b> , 140, 106454	2.8	12	
124	On the in-plane electronic thermal conductivity of biased nanosheet Eborophene. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 6318-6325	3.6	O	
123	Electronic structure and optical performance of PbI2/SnSe2 heterostructure. <i>Chemical Physics</i> , <b>2020</b> , 533, 110736	2.3	2	
122	Modulation of electronic and optical properties of GaTe monolayer by biaxial strain and electric field. Superlattices and Microstructures, <b>2020</b> , 140, 106435	2.8	4	
121	Half-metallicity and magnetism in BAs monolayer induced by anchoring 3d transition metals (TM = V, Cr and Mn). <i>Superlattices and Microstructures</i> , <b>2020</b> , 139, 106399	2.8	10	
120	Valence-band electronic structure and main optical properties of Cu2HgGeTe4: Theoretical simulation within a DFT framework and experimental XPS study. <i>Materials Today Communications</i> , <b>2020</b> , 23, 100828	2.5	4	
119	Computational insights into structural, electronic and optical characteristics of GeC/CN van der Waals heterostructures: effects of strain engineering and electric field RSC Advances, 2020, 10, 2967-2	2974	7	
118	Magneto-optical transport properties of monolayer transition metal dichalcogenides. <i>Physical Review B</i> , <b>2020</b> , 101,	3.3	44	
117	Promising optoelectronic response of 2D monolayer MoS2: A first principles study. <i>Chemical Physics</i> , <b>2020</b> , 538, 110824	2.3	6	
116	Functionalizing AlN monolayer with hydroxyl group: Effect on the structural and electronic properties. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , <b>2020</b> , 384, 126444	2.3	10	
115	A comprehensive investigation on electronic structure, optical and thermoelectric properties of the HfSSe Janus monolayer. <i>Journal of Physics and Chemistry of Solids</i> , <b>2020</b> , 144, 109490	3.9	14	
114	Highly anisotropic layered selenophosphate AgSbP2Se6: The electronic structure and optical properties by experimental measurements and first-principles calculations. <i>Chemical Physics</i> , <b>2020</b> , 536, 110813	2.3	2	
113	First-principles DFT computation and X-ray spectroscopy study of the electronic band structure and optical constants of Cu2HgGeS4. <i>Solid State Sciences</i> , <b>2020</b> , 104, 106287	3.4	7	
112	Electronic properties and low lattice thermal conductivity () of mono-layer (ML) MoS: FP-LAPW incorporated with spin-orbit coupling (SOC) <i>RSC Advances</i> , <b>2020</b> , 10, 18830-18840	3.7	13	
111	Fluorinating the graphene-like BeO monolayer: A spin-polarized first principles study of the electronic, magnetic and optical properties. <i>Physica Scripta</i> , <b>2020</b> , 95, 105806	2.6	7	
110	Simulation within a DFT framework and experimental study of the valence-band electronic structure and optical properties of quaternary selenide Cu2HgSnSe4. <i>Optik</i> , <b>2020</b> , 202, 163709	2.5	6	

109	Tuning the electronic, photocatalytic and optical properties of hydrogenated InN monolayer by biaxial strain and electric field. <i>Chemical Physics</i> , <b>2020</b> , 532, 110677	2.3	8
108	Graphene/WSeTe van der Waals heterostructure: Controllable electronic properties and Schottky barrier via interlayer coupling and electric field. <i>Applied Surface Science</i> , <b>2020</b> , 507, 145036	6.7	92
107	DFT-investigation on anisotropy degree of electronic, optical, and mechanical properties of olivine ZnRE2S4 (RE = Er, Tm) compounds. <i>Materials Research Express</i> , <b>2020</b> , 7, 016305	1.7	2
106	Reducing the electronic band gap of BN monolayer by coexistence of P(As)-doping and external electric field. <i>Superlattices and Microstructures</i> , <b>2020</b> , 137, 106357	2.8	9
105	Electronic and optical properties of wide band gap Tl3TaS4: A promising surface acoustic wave material. <i>Optical Materials</i> , <b>2020</b> , 99, 109601	3.3	5
104	Surface functionalization of GeC monolayer with F and Cl: Electronic and optical properties. <i>Superlattices and Microstructures</i> , <b>2020</b> , 137, 106359	2.8	10
103	Electronic and optical properties of 2D monolayer (ML) MoS2 with vacancy defect at S sites. <i>Nano Structures Nano Objects</i> , <b>2020</b> , 21, 100404	5.6	12
102	Structural and electronic properties of chemically functionalized SnC monolayer: a first principles study. <i>Materials Research Express</i> , <b>2020</b> , 7, 015013	1.7	8
101	Electronic, optical and photocatalytic properties of fully hydrogenated GeC monolayer. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 117, 113857	3	6
100	A type-II GaSe/HfS2 van der Waals heterostructure as promising photocatalyst with high carrier mobility. <i>Applied Surface Science</i> , <b>2020</b> , 534, 147607	6.7	40
99	Janus monolayer PtSSe under external electric field and strain: A first principles study on electronic structure and optical properties. <i>Superlattices and Microstructures</i> , <b>2020</b> , 147, 106683	2.8	39
98	Electronic structure and band alignment of Blue Phosphorene/Janus ZrSSe heterostructure: A first principles study. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 124, 114369	3	1
97	Optical and electronic properties of lithium thiogallate (LiGaS): experiment and theory <i>RSC Advances</i> , <b>2020</b> , 10, 26843-26852	3.7	4
96	Proposal of new spinel oxides semiconductors ZnGaO, [ZnGaO]:Mn and Rh: ab-initio calculations and prospects for thermophysical and optoelectronic applications. <i>Journal of Molecular Graphics and Modelling</i> , <b>2020</b> , 101, 107750	2.8	
95	Structural, electronic and optical properties of pristine and functionalized MgO monolayers: a first principles study <i>RSC Advances</i> , <b>2020</b> , 10, 40411-40420	3.7	3
94	Interfacial characteristics, Schottky contact, and optical performance of a graphene/Ga2SSe van der Waals heterostructure: Strain engineering and electric field tunability. <i>Physical Review B</i> , <b>2020</b> , 102,	3.3	55
93	Low-energy bands, optical properties, and spin/valley-Hall conductivity of silicene and germanene. <i>Journal of Materials Science</i> , <b>2020</b> , 55, 14848-14857	4.3	4
92	TlSbP2Se6 - a new layered single crystal: growth, structure and electronic properties. <i>Journal of Alloys and Compounds</i> , <b>2020</b> , 848, 156485	5.7	6

## (2019-2020)

91	Janus Ga2STe monolayer under strain and electric field: Theoretical prediction of electronic and optical properties. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 124, 114358	3	9	
90	Investigation of strain and doping on the electronic properties of single layers of CN and CN: a first principles study <i>RSC Advances</i> , <b>2020</b> , 10, 27743-27751	3.7	23	
89	Electronic, magnetic and optical properties of monolayer (ML) hexagonal ZnSe on vacancy defects at Zn sites from DFT-1/2 approach. <i>Vacuum</i> , <b>2020</b> , 182, 109597	3.7	8	
88	Efficient Broadband Truncated-Pyramid-Based Metamaterial Absorber in the Visible and Near-Infrared Regions. <i>Crystals</i> , <b>2020</b> , 10, 784	2.3	8	
87	Gas adsorption properties (N2, H2, O2, NO, NO2, CO, CO2, and SO2) on a Sc2CO2 monolayer: a first-principles study. <i>New Journal of Chemistry</i> , <b>2020</b> , 44, 18763-18769	3.6	8	
86	van der Waals heterostructures based on MSSe (M = Mo, W) and graphene-like GaN: enhanced optoelectronic and photocatalytic properties for water splitting. <i>Physical Chemistry Chemical Physics</i> , <b>2020</b> , 22, 20704-20711	3.6	11	
85	Spin-orbit coupling effect on electronic, optical, and thermoelectric properties of Janus GaSSe <i>RSC Advances</i> , <b>2020</b> , 10, 44785-44792	3.7	12	
84	Strain-tunable electronic and optical properties of monolayer GeSe: Promising for photocatalytic water splitting applications. <i>Chemical Physics</i> , <b>2020</b> , 529, 110543	2.3	41	
83	Computational understanding of the band alignment engineering in PbI2/PtS2 heterostructure: Effects of electric field and vertical strain. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2020</b> , 115, 113706	3	4	
82	Ternary sulfides BaLa2S4 and CaLa2S4 as promising photocatalytic water splitting and thermoelectric materials: First-principles DFT calculations. <i>International Journal of Hydrogen Energy</i> , <b>2020</b> , 45, 22600-22612	6.7	8	
81	Understanding the electronic properties, contact types and optical performances in graphene/InN heterostructure: Role of electric gating. <i>Diamond and Related Materials</i> , <b>2020</b> , 106, 107851	3.5	7	
80	Theoretical prediction of electronic and optical properties of haft-hydrogenated InN monolayers. <i>Superlattices and Microstructures</i> , <b>2020</b> , 142, 106519	2.8	4	
79	Tuning the electronic structure of 2D materials by strain and external electric field: Case of GeI2 monolayer. <i>Chemical Physics</i> , <b>2019</b> , 527, 110499	2.3	40	
78	Electronic and magnetic properties of single-layer boron phosphide associated with materials processing defects. <i>Computational Materials Science</i> , <b>2019</b> , 170, 109201	3.2	44	
77	Structural, electronic, optical and elastic properties of XLa2S4 (X = Ba; Ca): Ab initio study. <i>Physica B: Condensed Matter</i> , <b>2019</b> , 558, 91-99	2.8	5	
76	Tri-layered van der Waals heterostructures based on graphene, gallium selenide and molybdenum selenide. <i>Journal of Applied Physics</i> , <b>2019</b> , 125, 225304	2.5	10	
75	Tuning the electronic properties of GaS monolayer by strain engineering and electric field. <i>Chemical Physics</i> , <b>2019</b> , 524, 101-105	2.3	6	
74	Calculations within DFT framework of the electronic and optical properties of quaternary sulfide Tl2PbSiS4, a prospective optoelectronic semiconductor. <i>Computational Condensed Matter</i> , <b>2019</b> , 21, e0	003972	7	

73	Electronic and optical properties of quaternary sulfide Tl2HgSnS4, a promising optoelectronic semiconductor: A combined experimental and theoretical study. <i>Optical Materials</i> , <b>2019</b> , 92, 294-302	3.3	6
72	Assessing optoelectronic properties of PbI2 monolayer under uniaxial strain from first principles calculations. <i>Superlattices and Microstructures</i> , <b>2019</b> , 130, 354-360	2.8	25
71	Electronic and optical properties of layered van der Waals heterostructure based on MS2 (M = Mo, W) monolayers. <i>Materials Research Express</i> , <b>2019</b> , 6, 065060	1.7	7
70	First principles study of single-layer SnSe2 under biaxial strain and electric field: Modulation of electronic properties. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2019</b> , 111, 201-205	3	31
69	Electric field tunable electronic properties of P-ZnO and SiC-ZnO van der Waals heterostructures. <i>Computational Materials Science</i> , <b>2019</b> , 164, 166-170	3.2	20
68	A theoretical and experimental study of the valence-band electronic structure and optical constants of quaternary copper mercury tin sulfide, Cu2HgSnS4, a potential material for optoelectronics and solar cells. <i>Optical Materials</i> , <b>2019</b> , 96, 109296	3.3	23
67	Strain and electric field engineering of band alignment in InSe/Ca(OH)2 heterostructure. <i>Chemical Physics Letters</i> , <b>2019</b> , 732, 136649	2.5	5
66	Effect of DFT methods on electronic structure and K-absorption spectra of InPS4: detailed studies of the optical, thermoelectric and elastic properties. <i>Materials Research Express</i> , <b>2019</b> , 6, 106320	1.7	3
65	Tunable electronic properties of InSe by biaxial strain: from bulk to single-layer. <i>Materials Research Express</i> , <b>2019</b> , 6, 115002	1.7	2
64	Biaxial strain and external electric field effects on the electronic structure of hydrogenated GaN monolayer. <i>Superlattices and Microstructures</i> , <b>2019</b> , 136, 106270	2.8	9
63	Computational investigation of the structural, electronic, optical and thermoelectric properties of T2-Al2MgC2 compound. <i>Journal of Solid State Chemistry</i> , <b>2019</b> , 280, 120999	3.3	5
62	Rashba spin splitting and photocatalytic properties of GeCMSSe (M=Mo, W) van der Waals heterostructures. <i>Physical Review B</i> , <b>2019</b> , 100,	3.3	92
61	Strain-Tunable Electronic and Optical Properties of Monolayer Germanium Monosulfide: Ab-Initio Study. <i>Journal of Electronic Materials</i> , <b>2019</b> , 48, 2902-2909	1.9	8
60	Strain and electric field tunable electronic properties of type-II band alignment in van der Waals GaSe/MoSe2 heterostructure. <i>Chemical Physics</i> , <b>2019</b> , 521, 92-99	2.3	15
59	Structural properties and variable-range hopping conductivity of Cu2SnS3. <i>Materials Research Express</i> , <b>2019</b> , 6, 055915	1.7	4
58	Band alignment and optical features in Janus-MoSeTe/X(OH) (X = Ca, Mg) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 25849-25858	3.6	36
57	Tailoring the structural and electronic properties of an SnSe/MoS van der Waals heterostructure with an electric field and the insertion of a graphene sheet. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 22140-22148	3.6	32
56	Schottky anomaly and Nël temperature treatment of possible perturbed hydrogenated AA-stacked graphene, SiC, and h-BN bilayers <i>RSC Advances</i> , <b>2019</b> , 9, 41569-41580	3.7	5

## (2018-2019)

55	Electronic and optical properties of Janus ZrSSe by density functional theory <i>RSC Advances</i> , <b>2019</b> , 9, 41058-41065	3.7	45
54	Modulation of electronic properties of monolayer InSe through strain and external electric field. <i>Chemical Physics</i> , <b>2019</b> , 516, 213-217	2.3	14
53	Vertical strain and electric field tunable electronic properties of type-II band alignment C2N/InSe van der Waals heterostructure. <i>Chemical Physics Letters</i> , <b>2019</b> , 716, 155-161	2.5	30
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